Silicon Photodiode in Top-View **PLCC-2 Package**

OP980

Features:

- Wide acceptance angle, 100°
- · Fast response time
- Linear response vs Irradiance
- Plastic leadless chip carrier (PLCC-2)
- Low Capacitance
- Top Sensing Area
- Tape and reel packaging
- Moisture Sensitivity Level: MSL2 or >



electronics

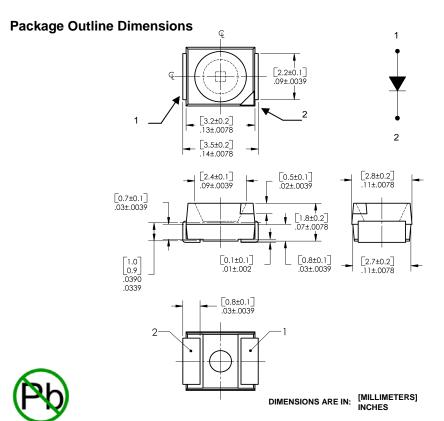
Description:

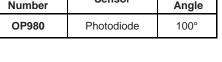
The **OP980** is a high speed, low-noise and high sensitivity PIN silicon photodiode mounted in a miniature SMD package. The device has a flat window lens, which enables a wide acceptance angle at 100°. Due to its clear lens, the OP980 responds to visible and near infrared light. It is packaged in a plastic leadless chip carrier that is compatible with most automated pick and place mounting equipment. The OP980 is mechanically and spectrally matched to the OP280 and OP180 infrared LED.

Applications:

- · Non-contact position sensing
- Datum detection
- · Computer peripherals
- Smoke detectors
- Touch Sensors
- Machine automation
- Optical encoders
- Reflective sensors
- · Counters and sorters
- Miniature optical switches

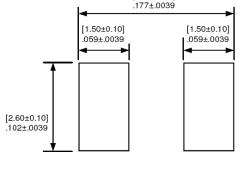
Ordering Information					
Part Number	Sensor	Viewing Angle			
OP980	Photodiode	100°			





Recommended Solder Patterns

[4.50±0.10]



Pin#	Transistor		
1	Anode		
2	Cathode		

RoHS

Silicon Photodiode in Top-View PLCC-2 Package OP980



Absolute Maximum Ratings (T_A=25°C unless otherwise noted)

Storage Temperature Range	-40° C to +100° C
Operating Temperature Range	-25° C to +85° C
Lead Soldering Temperature	260° C ⁽¹⁾

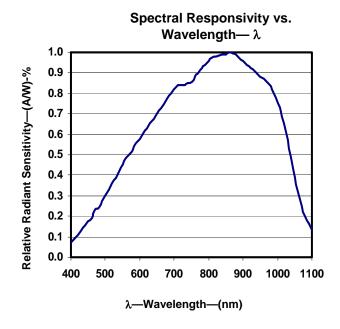
Electrical Characteristics (T_A = 25°C unless otherwise noted)

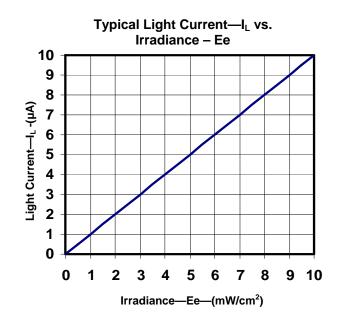
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
I∟	Light Current	0.5	ı	-	μΑ	$V_R = 5.0 \text{ V}, E_E = 1.0 \text{ mW/cm}^{2(3)}$
I _D	Dark Current	-	1	60	nA	$V_R = 30.0 \text{ V}, E_E = 0.0 \text{ mW/cm}^{2(3)}$
VR _(BR)	Reverse Breakdown Voltage	60		-	V	I _R = 10 μA
V _F	Forward Voltage	•	ı	1.2	V	$I_F = 1 \text{ mA}, \text{ Ee} = 0.0 \text{ mW/cm}^2$
λ_{pk}	Peak Sensitivity Wavelength	ı	890	-	nm	V _R = 5.0
tr	Rise Time	-	50	-	ns	$V_R = 5.0, R_L = 1k$
tf	Fall Time	-	50	-	ns	$V_R = 5.0, R_L = 1k$

Notes:

- 1. Solder time less than 5 seconds at temperature extreme.
- 2. Derate linearly at 1.33 mW/° C above 25° C.
- 3. E_{e(APT)} is an unfiltered GaAlAs LED with peak emission wavelength of 890nm. The measurement of the apertured radiant incidence upon a sensing area 0.081" (2.06mm) in diameter, perpendicular to and centered on the mechanical axis of the lens, and 0.590" (14.99mm) from the measurement surface. Measurement surface will be considered the tip of the top-view lens. E_{e(APT)} is not necessarily uniform within the measured area.

Electrical Characteristic Performance Curves



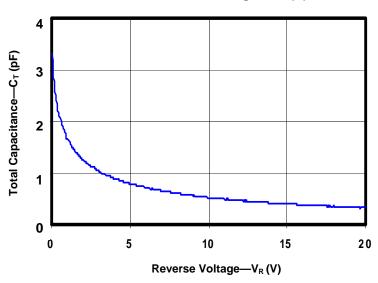


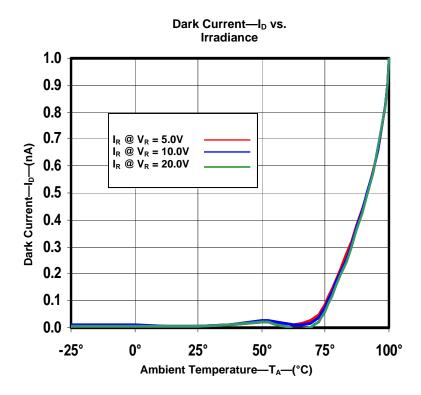
Silicon Photodiode in Top-View PLCC-2 Package OP980



More Typical Performance Curves

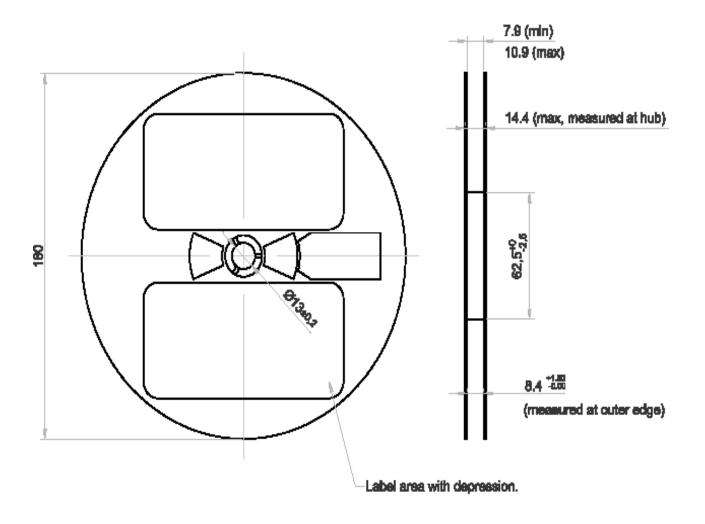
Total Capacitance— $C_T(pF)$ vs. Reverse Bias Voltage— $V_R(V)$







Reel Packaging Dimensions



Dimensions are in: mm Tolerance: ±0.01

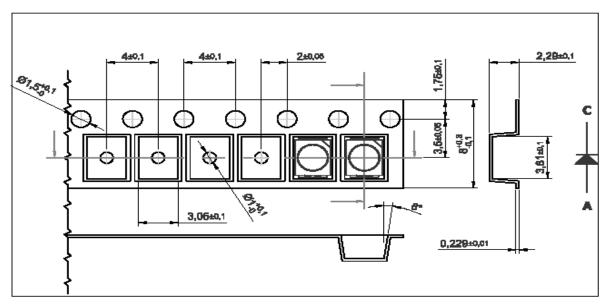
Silicon Photodiode in Top-View PLCC-2 Package

OPTEK Technology

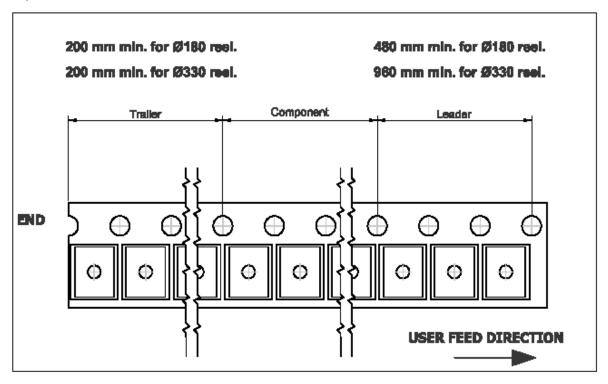
OP980

Taping and Orientation

- Reels come in quantity of 2000 units.
- Reel diameter is 180mm.



Tape Feed Direction



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Photodiodes category:

Click to view products by TT Electronics manufacturer:

Other Similar products are found below:

LTR-526AD OED-SP-7L LTR-536AB LTR-743DBM1-TA 67-21SYGC-S349-TR8 SFH 2200 A01 HFD3081-108-XBA BPW 34 S E9601
SFH 2713 SFH 2703 LTR-546AD BPV23FL BPW 34 FAS BPW 34 FS IG17X1000S4I IG22X250S4I VTD205H VTD205KH
VTP1232FH VTP4085H SFH 2400 OP913WSL OPF794 PD70-01C/TR7 LTR-536AD VTP8651H VTD206KH VTB1013H BPV23NF
OP905 LTR-516AD BPW 34 FS-Z VTD34FH QSB34CGR SFH 2500 FA PD15-22C/TR8 VEMD5510C SFH 2200 VEMD5510CF
SAH230M SAH230M2 SAH500M2 BP 104 FS BPV22F-AS12 BPW 21 BPW 34 SR-Z BPX 65 HSDL-5400#011 BPW 34 FASR BPW 34
FSR